

LINEAR PULSED POWER AMPLIFIER

Model – AP2.93.1G6050AC

General Description:

Elite RF's AP Series amplifier is a narrowband power amplifier designed for Pulsed signals fabricated on GaN on SiC process and can operate up to **3.1 GHz**. These amplifiers offer high power density, low thermal resistance, and narrowband performance. They can be widely used for military and commercial applications.

Like all Elite RF amplifiers, this product comes with an industry leading **5-year warranty**.



Features

Pulsed operation
High Pk. Output Power
High Gain
High Reverse Isolation
Built-in Protection

Indicator options

DC Power
Temp Fault

Protections

Thermal Overload
Over Voltage
Reverse Polarity

ELECTRICAL SPECIFICATIONS

Parameter	Symbol	Min	Typ	Max	Unit
Frequency Range	BW	2900		3100	MHz
Output Power Pk	Psat		1000		Watt
Duty Cycle	Dc		5	10	%
Small Signal Gain	Gp		50		dB
Gain Flatness	Delta Gp 1		+/- 1		dB
Input VSWR	S11		2:1		Ratio
Pulse width	Pw		50	100	uS
Harmonics	H		-20		dBc
Spurious Signals	Spur		-60		dBc
Operating Voltage	VAC	100	120	240	VAC
Average AC power at 1000 watts @ 10%	ACp		300		Watts
DC Class of Operation	C		AB		Class
Noise Figure	NF		7		dB
Large Signal Gain	Lsg		48		dB
Max Load VSWR @ 1000 Watts	ML		6:1		Ratio

ENVIRONMENTAL CHARACTERISTICS

Parameter	Symbol	Min	Typ	Max	Unit
Operating Case Temperature	Tc	-20		+60	Deg. C
Storage Temperature	Tstg	-40		+85	Deg. C
Relative Humidity (non-condensing)	RH			95	%
Altitude	ALT			10,000	Feet
Vibration/Shock	VI /SH				Normal Truck Transport

MECHANICAL CHARACTERISTICS

Parameter	Symbol	Min	Typ	Max	Unit
Dimensions	Dim		19" x 15" x 3.5"		Inches
Weight	Wt.		20		lbs.
Connectors In/Out	RF Conn		N/N Type		-
Cooling	Th		Internal		-

OPTIONS

Parameter	Add suffix to part number
Heat sink and fans	- H
Isolator with forward and reverse voltage outputs	N/A
TTL Input Trigger	- T

Mechanical Drawings

